

ISP752T

Smart power high-side-switch for industrial applications



Features

- Overload protection
- Current limitation
- Short circuit protection
- Thermal shutdown with restart
- ESD-protection
- Overvoltage protection (including load dump)
- Fast demagnetization of inductive loads
- Reverse battery protection with external resistor
- CMOS compatible input
- Loss of GND and loss of V_{bb} protection
- Very low standby current
- Green product (RoHS compliant)



Potential applications

- All types of resistive, inductive and capacitive loads
- μ C compatible power switch for 12 V, 24 V and 42 V DC industrial applications
- Replaces electromechanical relays and discrete circuits

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC JESD47/20/22.

Description

Parameter	Symbol	Value	Unit
Overvoltage protection	$V_{bb(AZ)}$	62	V
Operating voltage	$V_{bb(on)}$	6 to 52	V
On-state resistance	R_{ON}	200	m Ω
Nominal load current	$I_{L(nom)}$	1.3	A
Operating temperature	T_a	-30 to +85	$^{\circ}$ C

N channel vertical power FET with charge pump, ground referenced CMOS compatible input, monolithically integrated with embedded protective functions.

Type	Package	Marking
ISP752T	PG-DSO-8	I752T

Table of contents

	Features	1
	Potential applications	1
	Product validation	1
	Description	1
	Table of contents	2
1	Block diagram	3
2	Pin configuration	4
3	General product characteristics	5
3.1	Absolute maximum ratings	5
3.2	Thermal resistance	6
4	Functional description and electrical characteristics	7
4.1	Functional description	7
4.2	Electrical characteristics	10
4.3	Typical performance characteristics	12
4.4	Timing diagrams	17
5	Package information	19
	Revision history	20
	Disclaimer	21

Block diagram

1 Block diagram

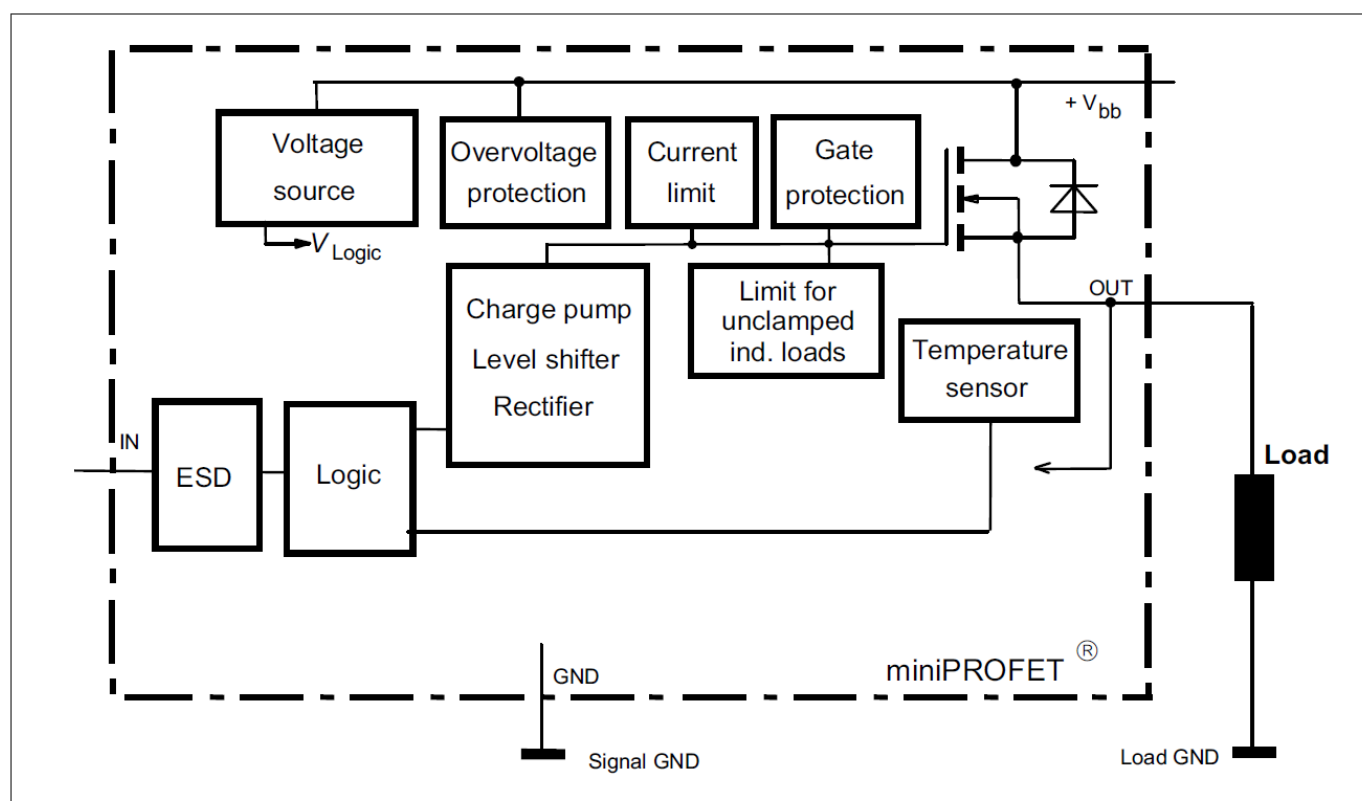


Figure 1 Block diagram

2 Pin configuration

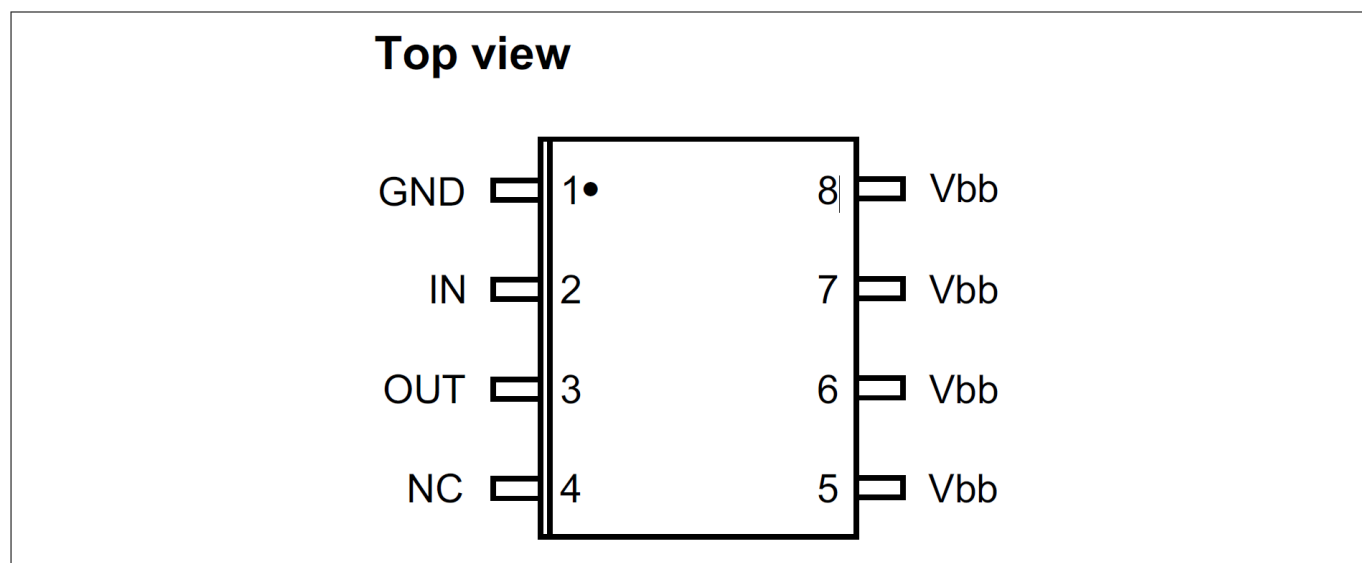


Figure 2 Pin configuration

Pin	Symbol	Function
1	GND	Logic ground
2	IN	Input, activates the power switch in case of logic high signal
3	OUT	Output to the load
4	NC	not connected
5	Vbb	Positive power supply voltage
6	Vbb	Positive power supply voltage
7	Vbb	Positive power supply voltage
8	Vbb	Positive power supply voltage

General product characteristics

3 General product characteristics

3.1 Absolute maximum ratings

Table 1 Maximum ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit	Note or condition
Supply voltage	V_{bb}	52	V	–
Supply voltage for full short circuit protection	$V_{bb(SC)}$	50	V	–
Continuous input voltage	V_{IN}	-10 to +16	V	–
Load current	I_L	self limited	A	short-circuit current, see page 11
Current through input pin (DC)	I_{IN}	± 5	mA	–
Junction temperature	T_j	150	$^\circ\text{C}$	–
Operating temperature	T_a	-30 to +85	$^\circ\text{C}$	–
Storage temperature	T_{stg}	-40 to +105	$^\circ\text{C}$	–
Power dissipation	P_{tot}	1.5	W	1)
Inductive load switch-off energy dissipation	E_{AS}	125	mJ	1) 2) single pulse (see page 7) $T_j = 150^\circ\text{C}$, $I_L = 1\text{ A}$
Load dump protection $R_L = 13.5\ \Omega$ $R_L = 27\ \Omega$	$V_{LoadDump}$	73.5 83.5	V	2) 3) $V_{LoadDump} = V_A + V_S$ $R_L = 2\ \Omega$, $t_d = 400\text{ ms}$, $V_{IN} = \text{low or high}$, $V_A = 13.5\text{ V}$
Electrostatic Discharge Voltage (Human Body Model) OUT IN all other pins	V_{ESD}	± 6 ± 1 ± 4	kV	according to ANSI/ESDA/JEDEC JS001 (1.5 k Ω , 100 pF)

¹ Device on 50 mm × 50 mm × 1.5 mm epoxy PCB FR4 with 6 cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air. (see page [19](#))

² Not subject to production test, specified by design

³ $V_{LoadDump}$ is set up without the DUT connected to the generator per ISO 7637-1 and DIN 40839. Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND pin, e.g. with a 150 Ω resistor in GND connection. A resistor for the protection of the input is integrated.

General product characteristics

3.2 Thermal resistance

Table 2 Thermal resistance

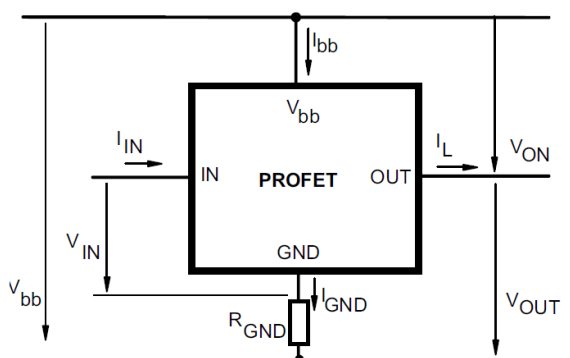
Parameter	Symbol	Values			Unit	Note or condition
		Min.	Typ.	Max.		
Thermal resistance minimum footprint 6 cm ² cooling area ⁴⁾	R _{th(JA)}	–	95 70	– 83	K/W	–

⁴ Device on 50 mm × 50 mm × 1.5 mm epoxy PCB FR4 with 6 cm² (one layer, 70 µm thick) copper area for drain connection. PCB is vertical without blown air. (see page [19](#))

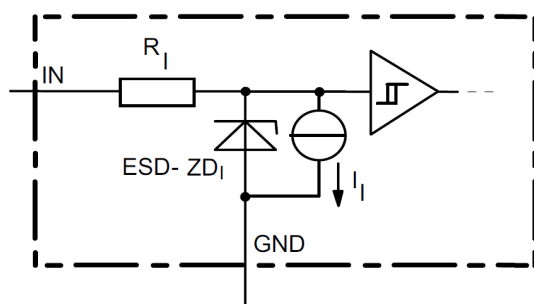
4 Functional description and electrical characteristics

4.1 Functional description

Terms

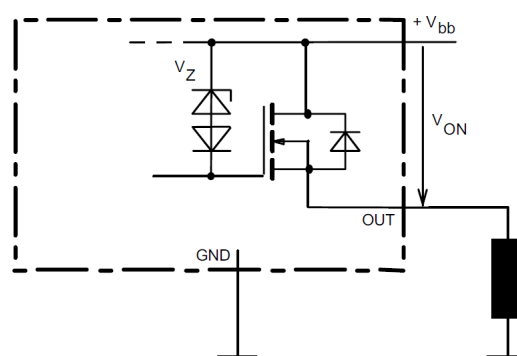


Input circuit (ESD protection)



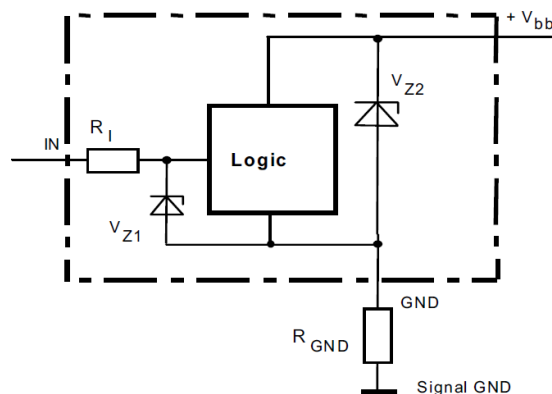
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

Inductive and overvoltage output clamp



V_{ON} clamped to 59 V min.

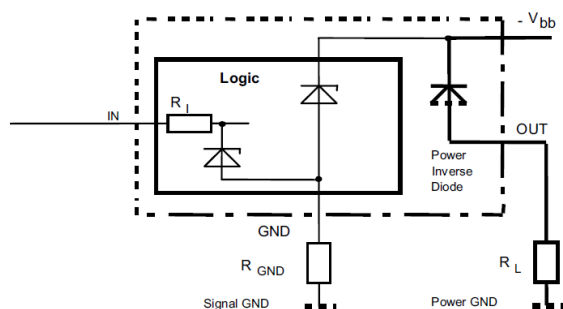
Overvoltage protection of logic part



$V_{Z1} = 6.1 \text{ V typ.}$, $V_{Z2} = V_{bb(AZ)} = 62 \text{ V min.}$, $R_I = 3.5 \text{ k}\Omega \text{ typ.}$, $R_{GND} = 150 \text{ }\Omega$

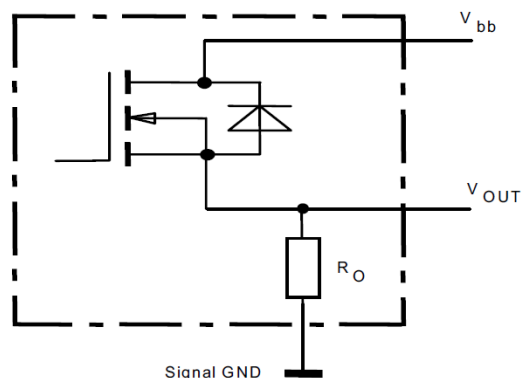
Functional description and electrical characteristics

Reverse battery protection



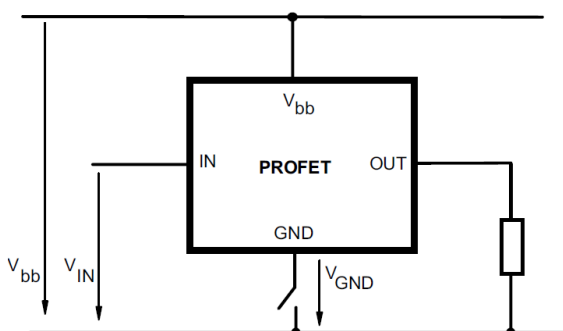
$R_{GND} = 150 \Omega$, $R_I = 3.5 \text{ k}\Omega$ typ., temperature protection is not active during inverse current

Internal output pull down

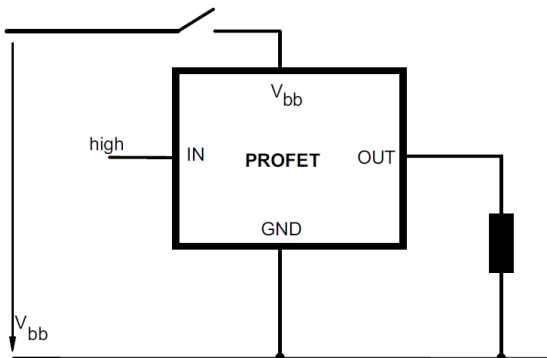


$R_O = 200 \text{ k}\Omega$ typ.

GND disconnect

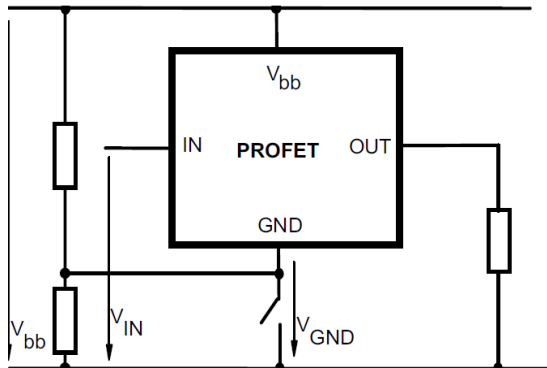


V_{bb} disconnect with charged inductive load

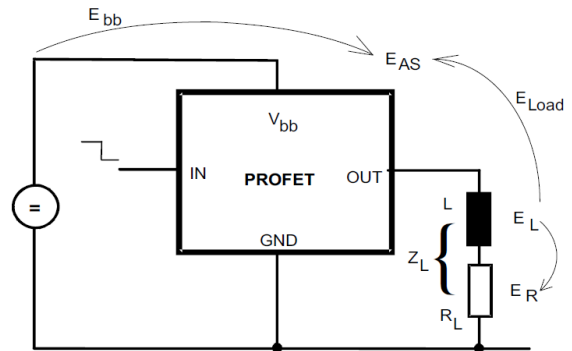


Functional description and electrical characteristics

GND disconnect with GND pull up



Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_L = \frac{1}{2} \times L \times I_L^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is:

$$E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} \times I_L(t) \, dt$$

with an approximate solution for $R_L > 0 \, \Omega$:

$$E_{AS} = \frac{I_L \times L}{2 \times R_L} \times (V_{bb} + |V_{UT(CL)}|) \times \ln \left(1 + \frac{I_L \times R_L}{|V_{OUT(CL)}|} \right)$$

Functional description and electrical characteristics

4.2 Electrical characteristics

Table 3 Electrical characteristics

$T_j = -40^\circ\text{C}$ to $+150^\circ\text{C}$, $V_{bb} = 12\text{ V}$ to 42 V , unless otherwise specified

Parameter	Symbol	Values			Unit	Note or condition
		Min.	Typ.	Max.		
Load switching capabilities and characteristics						
On-state resistance $T_j = 25^{\circ}\text{C}$, $I_L = 1\text{ A}$, $V_{bb} = 9\text{ V}$ to 52 V $T_j = 150^{\circ}\text{C}$	R_{ON}	– –	150 270	200 380	mΩ	–
Nominal load current	$I_{\text{L(nom)}}$	1.3	1.7	–	A	device on PCB ⁵⁾ $T_C = 85^{\circ}\text{C}$, $T_j \leq 150^{\circ}\text{C}$
Turn-on time to 90% V_{OUT}	t_{on}	–	80	180	μs	$R_L = 47\ \Omega$
Turn-off time to 10% V_{OUT}	t_{off}	–	80	200	μs	$R_L = 47\ \Omega$
Slew rate on 10% to 30% V_{OUT}	dV/dt_{on}	–	0.7	2	V/μs	$R_L = 47\ \Omega$, $V_{bb} = 13.5\text{ V}$
Slew rate off 70% to 40% V_{OUT}	$-dV/dt_{\text{off}}$	–	0.9	2	V/μs	$R_L = 47\ \Omega$, $V_{bb} = 13.5\text{ V}$

Operating parameters

Operating voltage	$V_{bb(on)}$	6	–	52	V	
Undervoltage shutdown of charge pump $T_j = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$V_{bb(under)}$	–	–	4 5.5	V	–
Undervoltage restart of charge pump	$V_{bb(u\ cp)}$	–	4	5.5	V	–
Standby current $T_j = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{IN} = \text{low}$ $T_j = +150^\circ\text{C}$ ⁶⁾ , $V_{IN} = \text{low}$	$I_{bb(off)}$	–	–	15 18	μA	–
Leakage output current	$I_{L(off)}$	–	–	5	μA	included in $I_{bb(off)}$ $V_{IN} = \text{low}$
Operating current $V_{IN} = \text{high}$	I_{GND}	–	0.8	2	mA	–

Protection functions ⁷⁾

⁵⁾ Device on 50 mm × 50 mm × 1.5 mm epoxy PCB FR4 with 6 cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air. (see page 19)

⁶⁾ Higher current due temperature sensor

⁷⁾ Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

Functional description and electrical characteristics

Table 3 **Electrical characteristics (continued)**

$T_j = -40^\circ\text{C}$ to $+150^\circ\text{C}$, $V_{bb} = 12\text{ V}$ to 42 V , unless otherwise specified

Parameter	Symbol	Values			Unit	Note or condition
		Min.	Typ.	Max.		
Initial peak short circuit current limit (pin 5 to 3) $T_j = -40^\circ\text{C}$, $V_{bb} = 20\text{ V}$, $t_m = 150\text{ }\mu\text{s}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$ $T_j = -40^\circ\text{C}$ to $+150^\circ\text{C}$, $V_{bb} > 40\text{ V}$	$I_{L(SCP)}$	–	–	9	A	–
		–	6.5	–		–
		4	–	–		–
		–	5 ⁸⁾	–		(see page 14)
Repetitive short circuit current limit $T_j = T_{jt}$ $V_{bb} < 40\text{ V}$ $V_{bb} > 40\text{ V}$	$I_{L(SCR)}$	–	6	–	A	(see Timing diagrams)
		–	4.5	–		
Output clamp (inductive load switch off)	$V_{ON(CL)}$	59	63	–	V	$V_{OUT} = V_{bb} - V_{ON(CL)}$, $I_{bb} = 4\text{ mA}$
Overvoltage protection	$V_{bb(AZ)}$	62	–	–	V	⁹⁾ $I_{bb} = 4\text{ mA}$
Thermal overload trip temperature	T_{jt}	150	–	–	$^\circ\text{C}$	–
Thermal hysteresis	ΔT_{jt}	–	10	–	K	–

Reverse battery

Reverse battery	$-V_{bb}$	–	–	52	V	¹⁰⁾
Drain-source diode voltage ($V_{OUT} > V_{bb}$)	$-V_{ON}$	–	600	–	mV	$T_j = 150^\circ\text{C}$

Input

Input turn-on threshold voltage	$V_{IN(T+)}$	–	–	2.2	V	–
Input turn-off threshold voltage	$V_{IN(T-)}$	0.8	–	–	V	–
Input threshold hysteresis	$\Delta V_{IN(T)}$	–	0.4	–	V	–
Off state input current	$I_{IN(off)}$	1	–	25	μA	$V_{IN} = 0.7\text{ V}$
On state input current	$I_{IN(on)}$	3	–	25	μA	$V_{IN} = 5\text{ V}$
Input resistance	R_I	2	3.5	5	k Ω	see page 7

⁸ Not subject to production test, specified by design

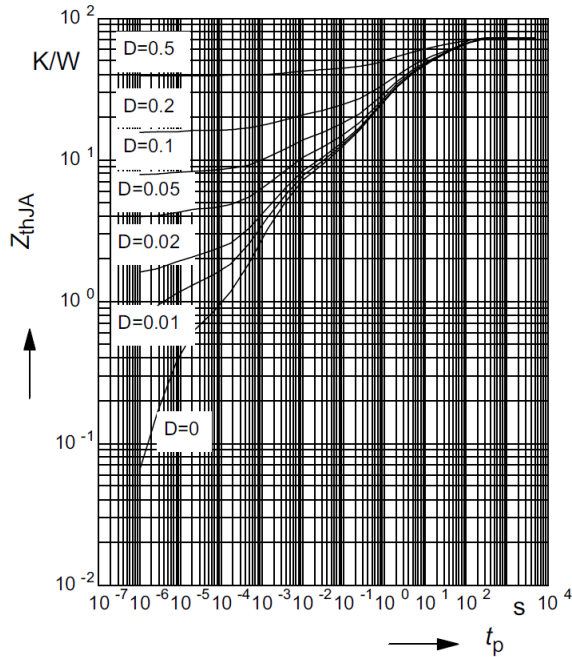
⁹ See also $V_{ON(CL)}$ in circuit diagram on page 7

¹⁰ Requires a $150\text{ }\Omega$ resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input current has to be limited (see [Absolute maximum ratings](#) on page 5).

4.3 Typical performance characteristics

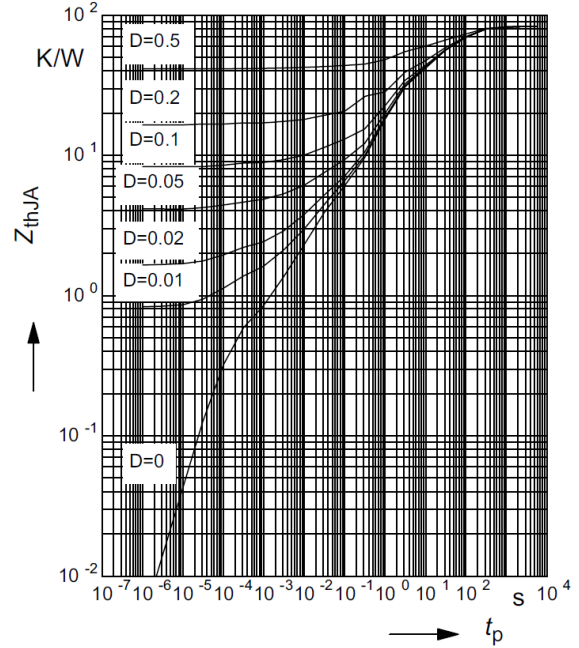
Typ. transient thermal impedance $Z_{thJA} = f(t_p)$
@ 6 cm² heatsink area

Parameter: $D = t_p/T$



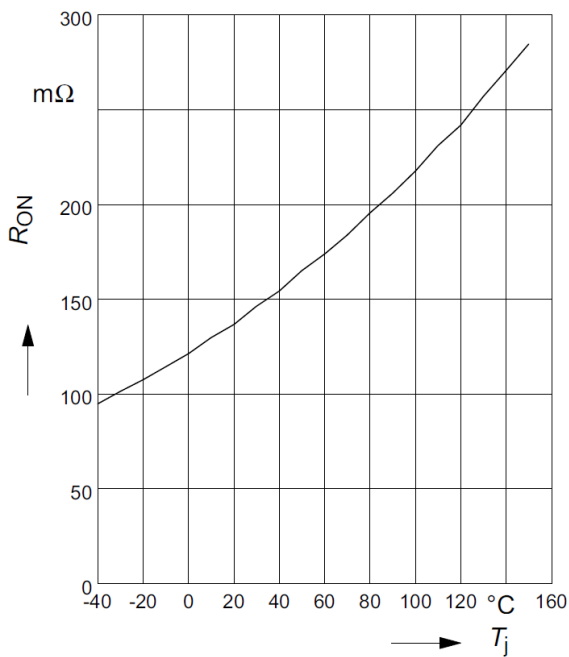
Typ. transient thermal impedance $Z_{thJC} = f(t_p)$
@ minimum footprint

Parameter: $D = t_p/T$



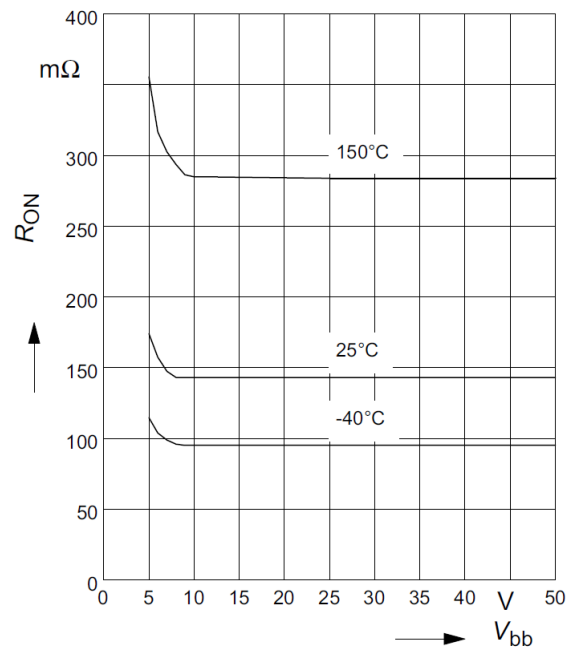
Typ. on-state resistance $R_{ON} = f(T_j)$

$V_{bb} = 13.5$ V; $V_{IN} = \text{high}$



Typ. on-state resistance $R_{ON} = f(V_{bb})$

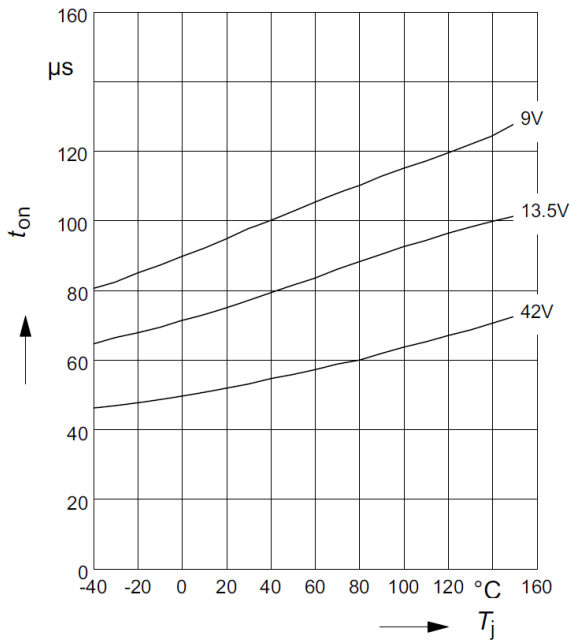
$I_L = 1$ A; $V_{IN} = \text{high}$



Functional description and electrical characteristics

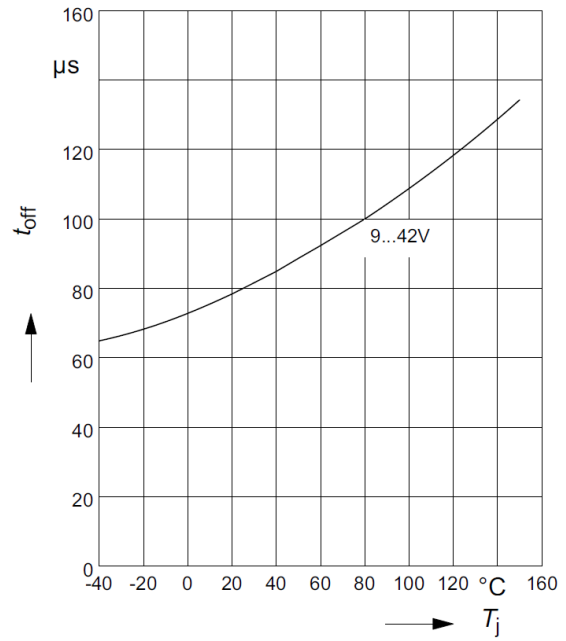
Typ. turn-on time $t_{on} = f(T_j)$

$R_L = 47 \Omega$



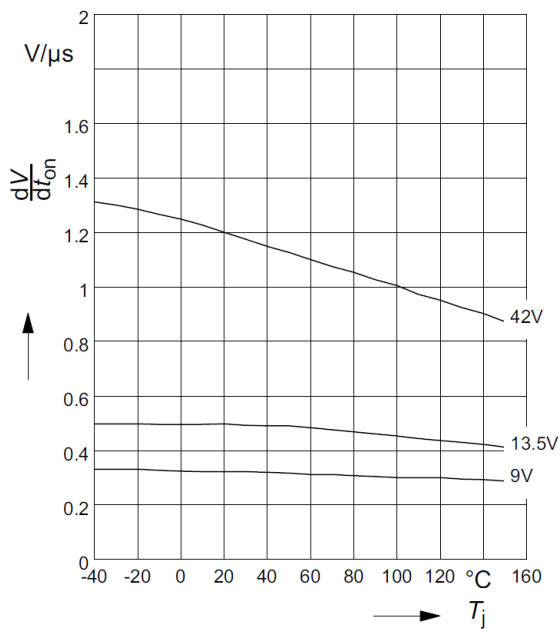
Typ. turn-off time $t_{off} = f(T_j)$

$R_L = 47 \Omega$



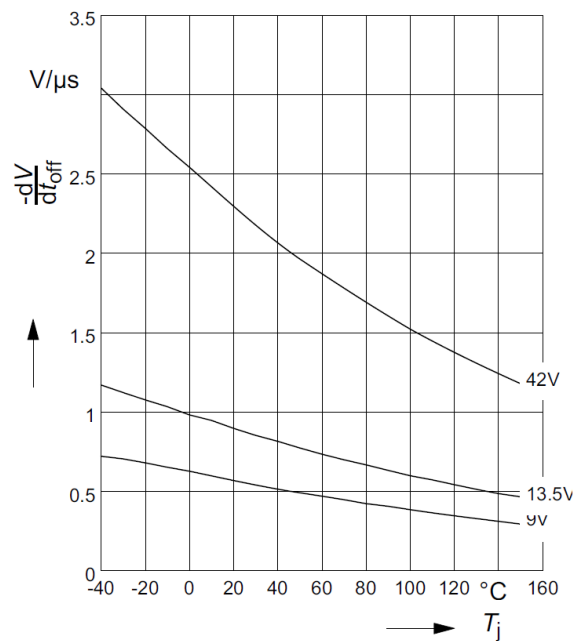
Typ. slew rate on $dV/dt_{on} = f(T_j)$

$R_L = 47 \Omega$



Typ. slew rate off $dV/dt_{off} = f(T_j)$

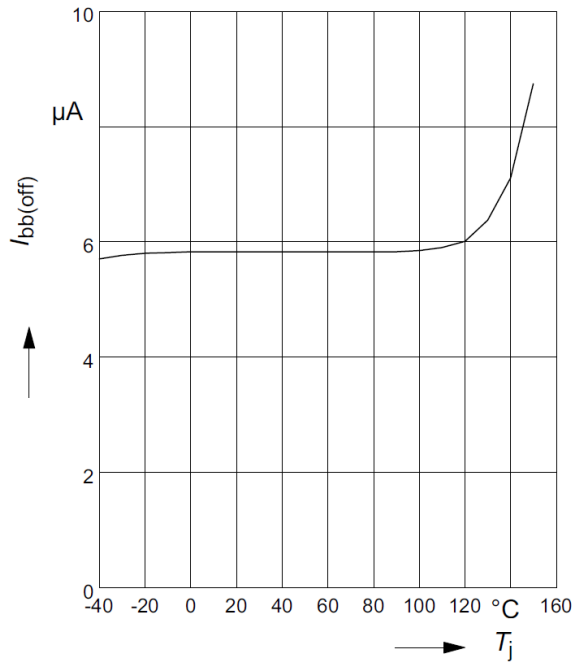
$R_L = 47 \Omega$



Functional description and electrical characteristics

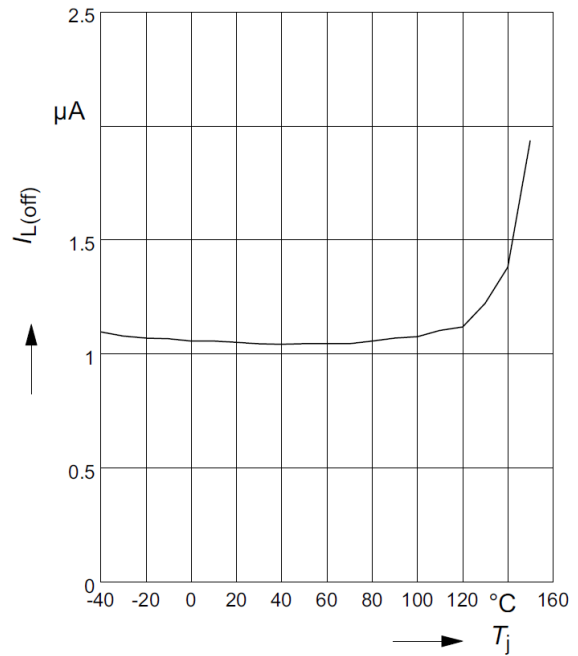
Typ. standby current $I_{bb(off)} = f(T_j)$

$V_{bb} = 42 \text{ V}$; $V_{IN} = \text{low}$

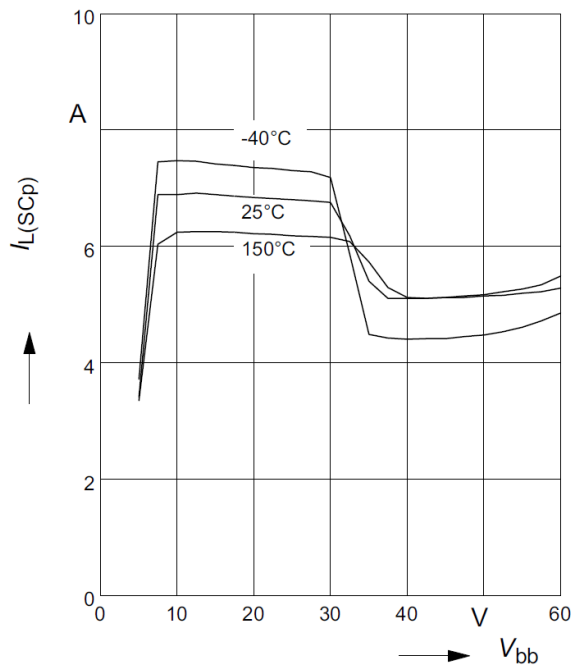


Typ. leakage current $I_{L(off)} = f(T_j)$

$V_{bb} = 42 \text{ V}$; $V_{IN} = \text{low}$

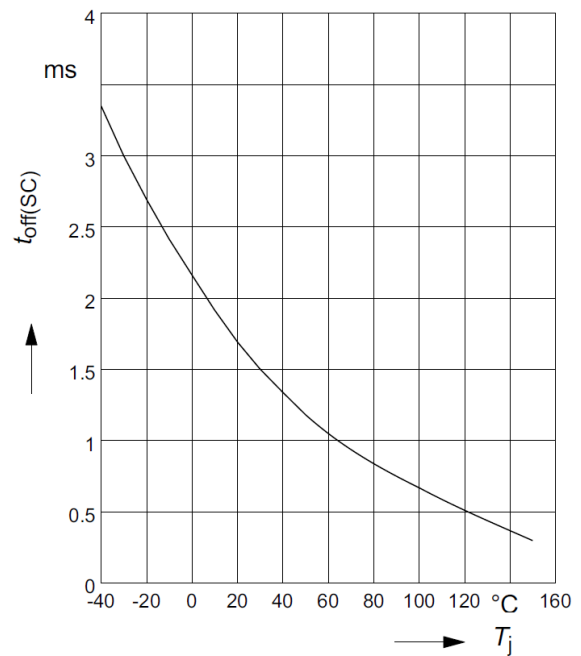


Typ. initial peak short circuit current limit $I_{L(SCp)} = f(V_{bb})$



Typ. initial short circuit shutdown time $t_{off(SC)} = f(T_j, \text{start})$

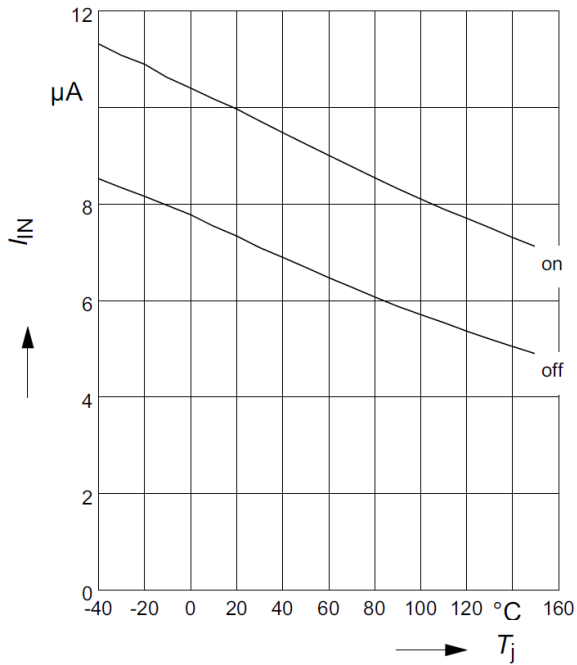
$V_{bb} = 20 \text{ V}$



Functional description and electrical characteristics

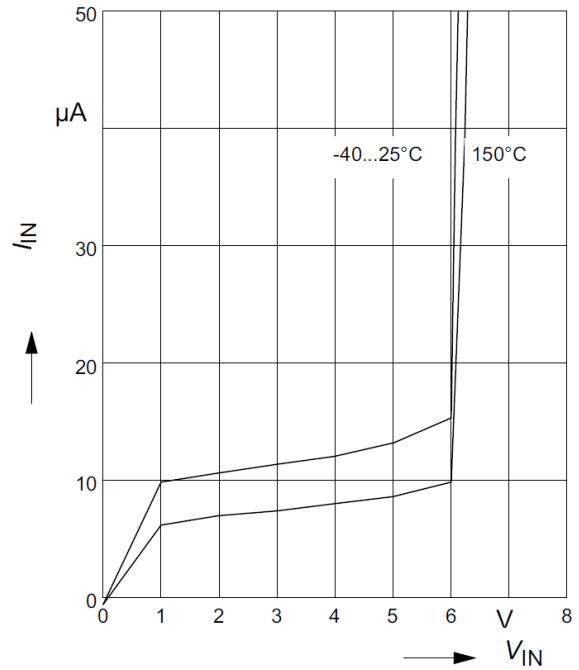
Typ. input current $I_{IN(on/off)} = f(T_j)$

$V_{bb} = 13.5 \text{ V}$; $V_{IN} = \text{low/high}$; $V_{INlow} \leq 0.7 \text{ V}$; $V_{INhigh} = 5 \text{ V}$



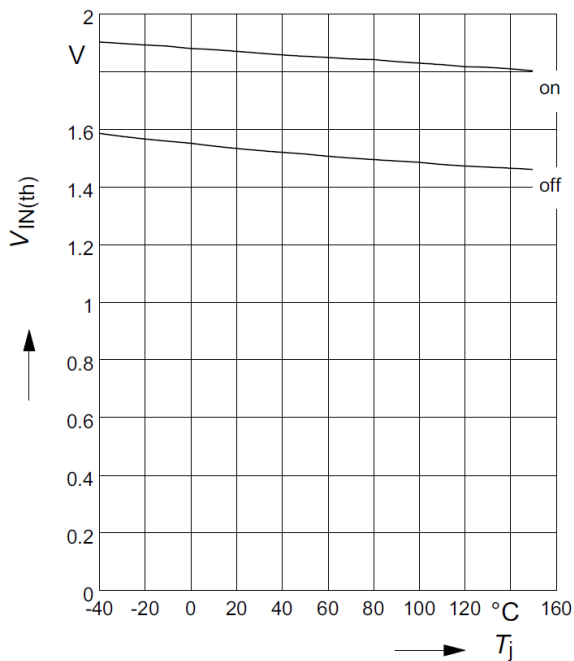
Typ. input current $I_{IN} = f(V_{IN})$

$V_{bb} = 13.5 \text{ V}$



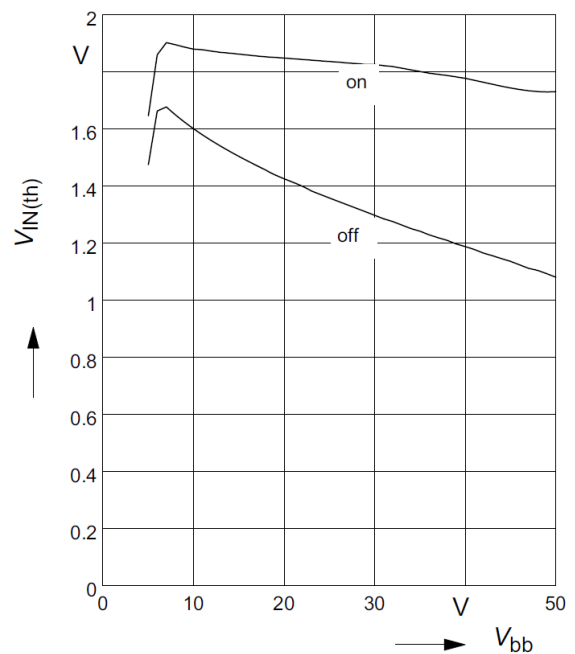
Typ. input threshold voltage $V_{IN(th)} = f(T_j)$

$V_{bb} = 13.5 \text{ V}$



Typ. input threshold voltage $V_{IN(th)} = f(V_{bb})$

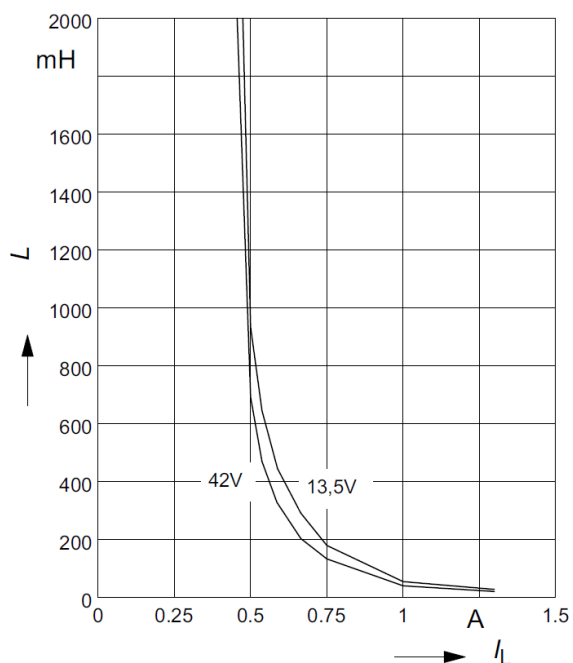
$T_j = 25^\circ\text{C}$



Functional description and electrical characteristics

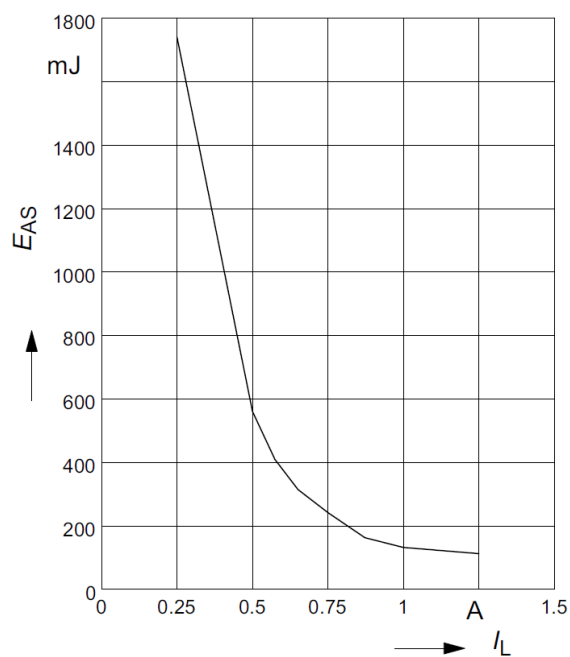
Maximum allowable load inductance for a single switch off $L = f(I_L)$

$T_{jstart} = 150^{\circ}\text{C}$, $R_L = 0\ \Omega$



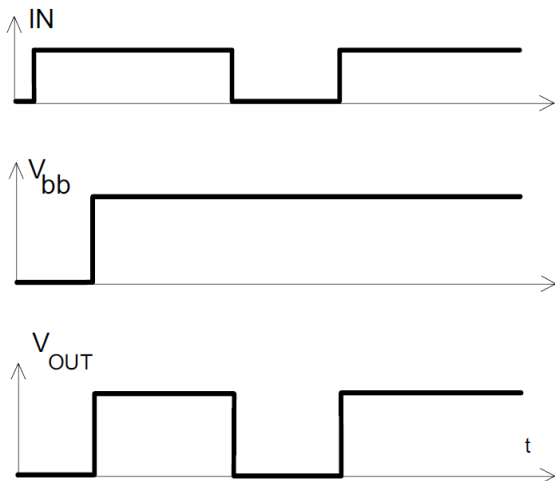
Maximum allowable inductive switch off energy, single pulse $E_{AS} = f(I_L)$

$T_{jstart} = 150^{\circ}\text{C}$, $V_{bb} = 13.5\ \text{V}$

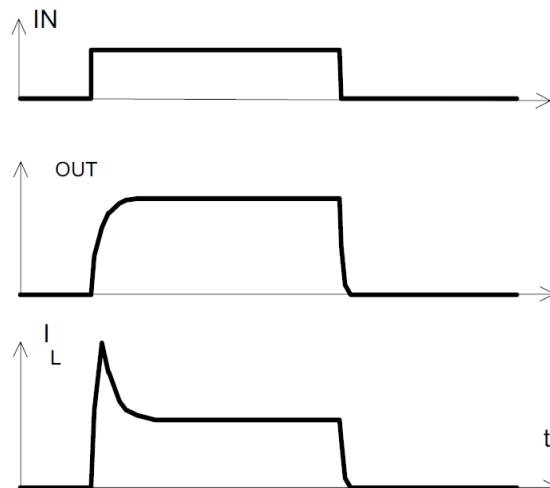


4.4 Timing diagrams

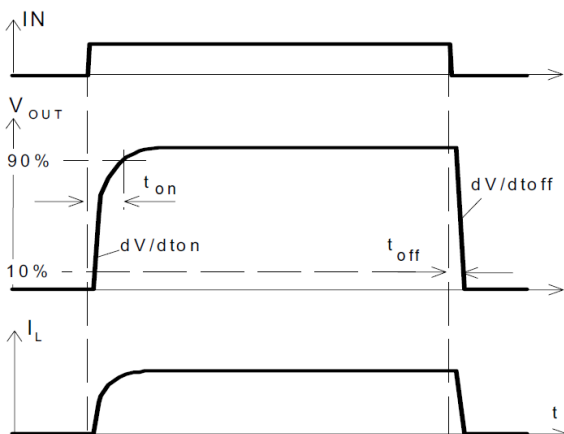
V_{bb} turn on



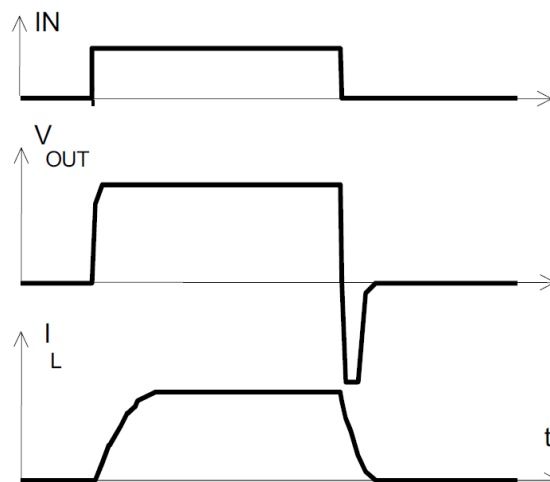
Switching a lamp



Switching a resistive load, turn-on/off time and slew rate definition

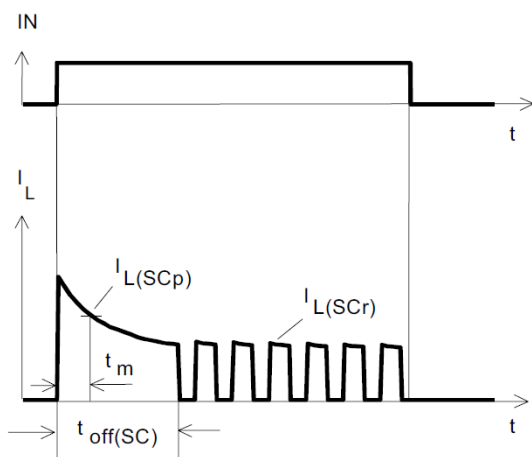


Switching an inductive load



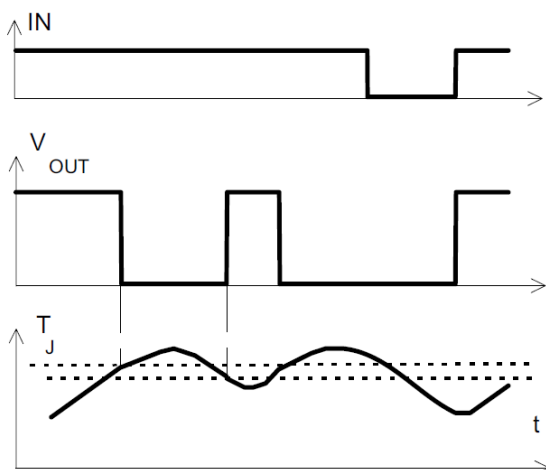
Functional description and electrical characteristics

Turn on into short circuit, shut down by overtemperature, restart by cooling

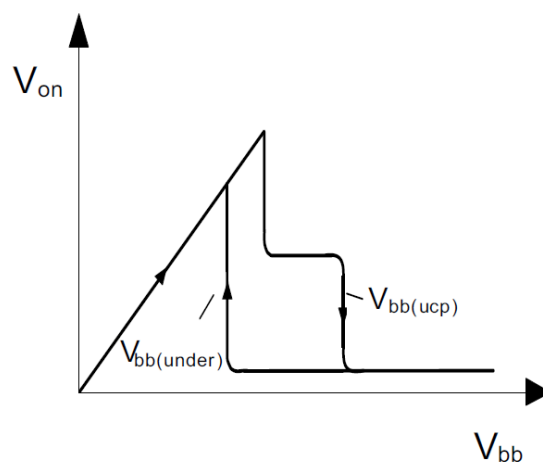


Heating up of the chip may require several milliseconds, depending on external conditions.

Overtemperature: Reset if $T_j < T_{jt}$



Undervoltage restart of charge pump



5 Package information

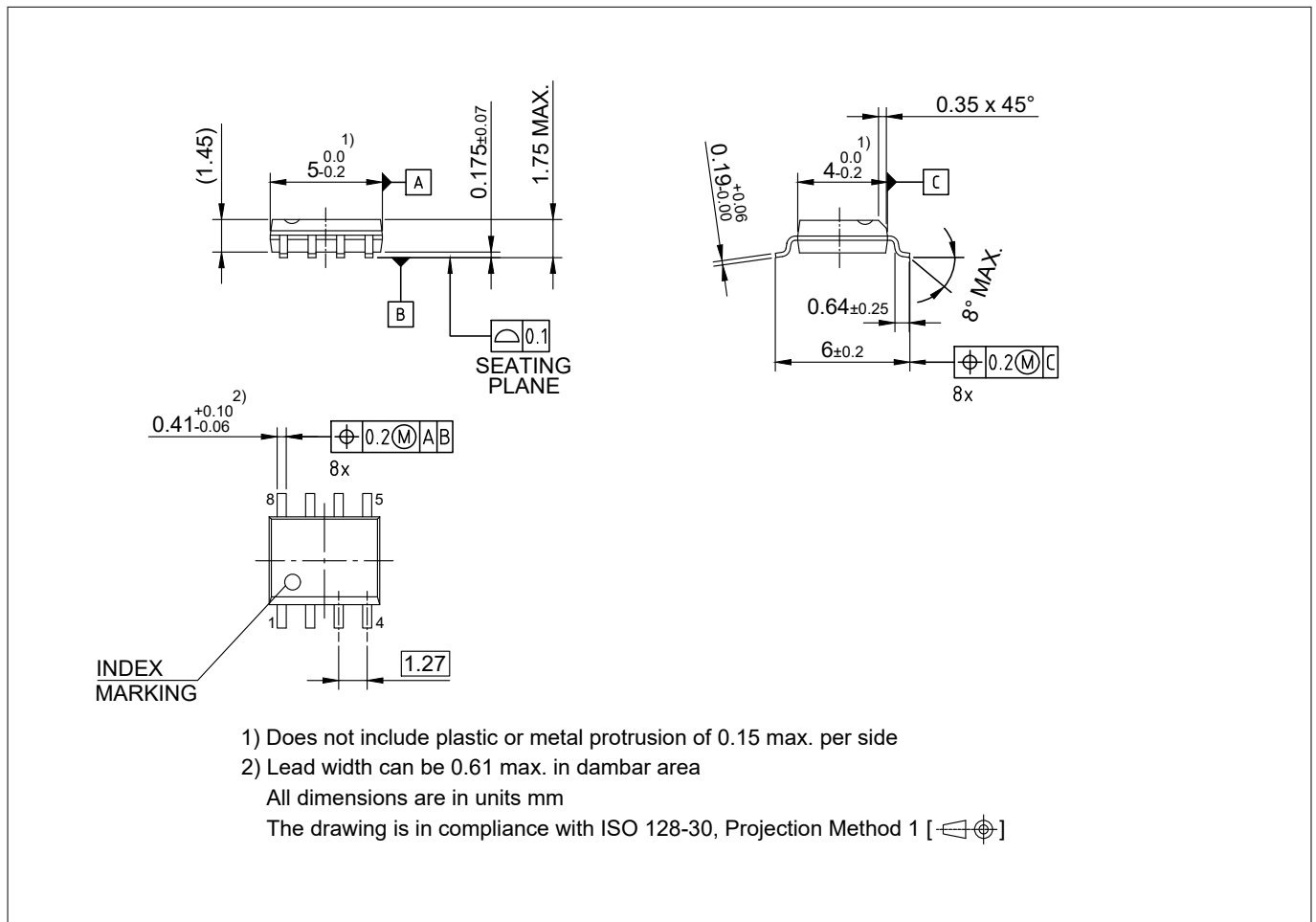


Figure 3 PG-DSO-8

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Information on alternative packages

Please visit www.infineon.com/packages.

Revision history

Revision history

Revision	Date	Changes
1.2	2019-07-25	All pages: • ESD ratings for HBM updated according to ANSI/ESDA/JEDEC JS-001 • Editorial changes
1.1	2008-09-26	All pages: • added new Infineon logo • Initial version of RoHS-compliant derivate of the ISP752T Page 1 and 17: • Added RoHS compliance statement and Green product feature • Package changed to RoHS compliant version Page 18: added Revision history Page 19: update of disclaimer

Trademarks

All referenced product or service names and trademarks are the property of their respective owners.

Edition 2019-07-25

Published by

Infineon Technologies AG
81726 Munich, Germany

© 2019 Infineon Technologies AG
All Rights Reserved.

Do you have a question about any aspect of this document?

Email: erratum@infineon.com

Document reference
IFX-Z8F64610016

IMPORTANT NOTICE

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenhheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

Please note that this product is not qualified according to the AEC Q100 or AEC Q101 documents of the Automotive Electronics Council.

WARNINGS

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Infineon:](#)

[ISP752T](#)